







SN54AC14, SN74AC14

SCAS522H - AUGUST 1995 - REVISED JANUARY 2023

Hex Schmitt-Trigger Inverters

1 Features

- V_{CC} operation of 2 V to 6 V
- Inputs accept voltages to 6 V
- Max t_{pd} of 9.5 ns at 5 V

2 Applications

- Synchronize inverted clock inputs
- Debounce a switch
- Invert a digital signal

3 Description

These Schmitt-trigger devices contain six independent inverters.

Package Information

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOIC	8.65 mm x 3.9 mm
	SSOP	6.2 mm x 1.95 mm
SNx4AC14	PDIP	19.3 mm x 6.35 mm
	SOP	10.3 mm x 5.3 mm
	TSSOP	5.00 mm x 4.4 mm





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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (August 2008) to Revision H (January 2023)

Page



5 Pin Configuration and Functions

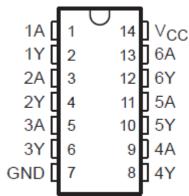
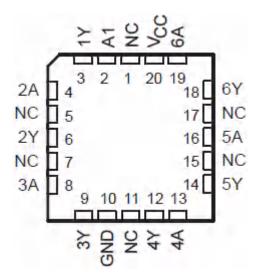


Figure 5-1. SN54AC14 J or W Package and SN74AC14 D, DB, N, NS, or PW Package Top View



NC - No internal connection

Figure 5-2. SN54AC14 FK Package Top View



Pin Functions

	PIN			
NAME	D, DB, N, NS, PW, J, or W	FK	I/O	DESCRIPTION
1A	1	2	Input	Channel 1, Input A
1Y	2	3	Output	Channel 1, Output Y
2A	3	4	Input	Channel 2, Input A
2Y	4	6	Output	Channel 2, Output Y
3A	5	8	Input	Channel 3, Input A
3Y	6	9	Output	Channel 3, Output Y
GND	7	10	_	Ground
4Y	8	12	Output	Channel 4, Output Y
4A	9	13	Input	Channel 4, Input A
5Y	10	14	Output	Channel 5, Output Y
5A	11	16	Input	Channel 5, Input A
6Y	12	18	Output	Channel 6, Output Y
6A	13	19	Input	Channel 6, Input A
V _{CC}	14	20	_	Positive Supply
NC		1, 5, 7, 11, 15, 17	_	Not internally connected



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted(1)

		UNIT
Supply voltage range, V _{CC}	-0.5 V to 7	V
Input voltage range, V _I (⁽²⁾)	-0.5 V to V _{CC} + 0.5	V
Output voltage range, V _O (⁽²⁾)	-0.5 V to V _{CC} + 0.5	V
Input clamp current, I_{IK} ($V_1 < 0$ or $V_1 > V_{CC}$)	±20	mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20	mA
Continuous output current, I _O (V _O = 0 to V _{CC})	±50	mA
Continuous current through V _{CC} or GND	±200	mA
Storage temperature range, T _{stg}	-65 to 150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±4000	
$V_{(ESD)}$	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±2000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommend Operating Conditions

			SN54A	C14	SN74A0	C14	UNIT
			MIN	MAX	MIN	MAX	UNII
V _{CC}	Supply voltage		2	6	2	6	V
VI	Input voltage		0	V _{CC}	0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	0	V _{CC}	V
		V _{CC} = 3 V		-12		-12	
I _{OH}	High-level output current	V _{CC} = 4.5 V		-24		-24	mA
		V _{CC} = 5.5 V		-24		-24	
		V _{CC} = 3 V		12		12	
I _{OL}	Low-level output current	V _{CC} = 4.5 V		24		24	mA
		V _{CC} = 5.5 V		24		24	
T _A	Operating free-air temperature		-55	125	-40	85	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾				SNx4AC14						
		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT			
				14 PINS						
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	96	80	76	113	°C/W			

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		T	₄ = 25°C		SN54A	C14	SN74A	C14	LINUT
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
V _{T+}		3 V	0.8	1.8	2.2	0.8	2.2	0.8	2.2	
Positive-going		4.5 V	1.5	2.6	3.2	1.5	3.2	1.5	3.2	V
threshold		5.5 V	1.6	3.2	3.9	1.6	3.9	1.6	3.9	
V _{T-}		3 V	0.5	0.8	1	0.5	1.2	0.5	1	
Negative-going		4.5 V	0.9	1.4	1.8	0.9	1.8	0.9	1.8	V
threshold		5.5 V	1.1	1.8	2.3	1.1	2.3	1.1	2.3	
ΔV_{T}		3 V	0.3	1	1.2	0.3	1.2	0.3	1.2	
Hysteresis		4.5 V	0.4	1.2	1.4	0.4	1.4	0.4	1.4	V
(V _{T+} - V _{T-})		5.5 V	0.5	1.4	1.6	0.5	1.6	0.5	1.6	
		3 V	2.9			2.9		2.9		
	I _{OH} = -50 μA	4.5 V	4.4			4.4		4.4		
		5.5 V	5.4			5.4		5.4		
\	I _{OH} = -12 mA	3 V	2.56			2.4		2.48		V
V _{OH}	I _{OH} = -24 mA	4.5 V	3.86			3.7		3.8		V
	10H24 IIIA	5.5 V	4.86			4.7		4.8		
	$I_{OH} = -50 \text{ mA}^{(1)}$	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{(1)}$	3.5 V						3.85		
		3 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	
		5.5 V			0.1		0.1		0.1	
V _{OL}	I _{OL} = 12 mA	3 V			0.36		0.44		0.44	V
VOL.	I _{OL} = 24 mA	4.5 V			0.36		0.44		0.44	V
	IOL - 24 IIIA	5.5 V			0.36		0.44		0.44	
	I _{OL} = 50 mA ⁽¹⁾	5.5 V					1.65			
	$I_{OL} = 75 \text{ mA}^{(1)}$	3.5 V							1.65	
I ₁	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		40		20	μΑ
C _i	V _I = V _{CC} or GND	5 V		4.5						pF

⁽¹⁾ Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

6.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	TA	= 25°C		SN54A	C14	SN74	AC14	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII
t _{PLH}	٨	V	1.5	6	13.5	1	16	1.5	15	ne
t _{PHL}	^	1	1.5	6	11.5	1	14	1.5	13	ns



6.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	TA	= 25°C		SN54A	C14	SN74A	C14	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII
t _{PLH}	۸	V	1.5	5	10	1.5	12	1.5	11	ne
t _{PHL}		'	1.5	5	8.5	1.5	10	1.5	9.5	ns

6.8 Operating Characteristics

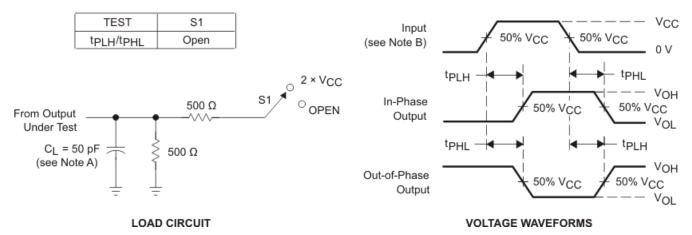
 V_{CC} = 5 V, T_A = 25°C

PARAMETER		NDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	C _L = 50 pF,	f = 1 MHz	25	pF



7 Parameter Measurement Information

7.1



- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

These 'AC14 devices perform the Boolean function $Y = \overline{A}$. Because of the Schmitt action, they have different input threshold levels for positive-going (V_{T+}) and for negative-going (V_{T-}) signals.

These circuits are temperature compensated and can be triggered from the slowest of input ramps and still give clean, jitter-free output signals. They also have a greater noise margin than conventional inverters.

8.2 Functional Block Diagram



8.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows up voltage translation from 3.3 V to 5 V
 - Inputs accept V_{IH} levels of 2 V
- · Slow edge rates minimize output ringing
- · Inputs are TTL-Voltage compatible

8.3.1 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

Unused push-pull CMOS outputs should be left disconnected.

8.3.2 Clamp Diode Structure

As shown in Figure 8-1, the inputs and outputs to this device have both positive and negative clamping diodes.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

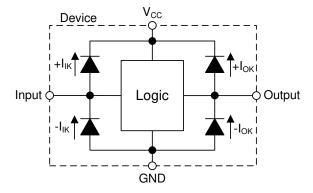


Figure 8-1. Electrical Placement of Clamping Diodes for Each Input and Output



8.4 Device Functional Modes

Table 8-1. Function Table

INPUT	OUTPUT
Α	Y
Н	L
L	Н

9 Application Information Disclaimer

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SNx4AC14 device is a low-drive CMOS device that can be used for a multitude of bus interface type applications where putput ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs are tolerant to 5.5 V at any valid V_{CC} . This feature makes it Ideal for translating down to the V_{CC} level. Switching Characteristics Comparison shows the reduction in ringing compared to higher drive parts such as AC.

9.2 Typical Application

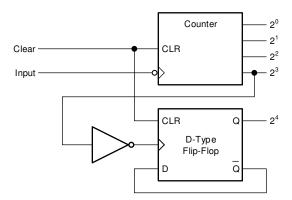


Figure 9-1. Typical Application Schematic

9.2.1 Design Requirements

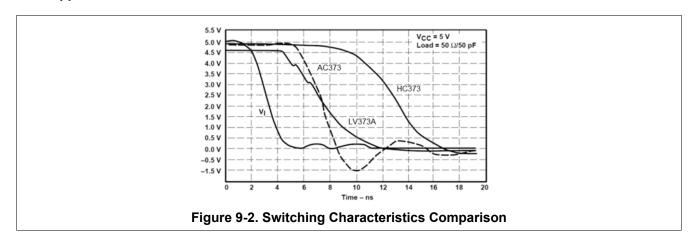
This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in the Section 6.3 table.
 - For specified High and low levels, see V_{IH} and V_{IL} in the Section 6.3 table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



9.2.3 Application Curves



9.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 6.3.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended; if there are multiple V_{CC} pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and a 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

9.4 Layout

9.4.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Layout Diagram are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

9.4.2 Layout Example

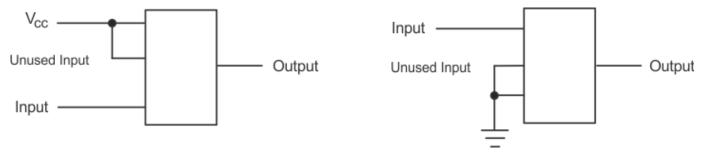


Figure 9-3. Layout Diagram



10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 10-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54AC14	Click here	Click here	Click here	Click here	Click here	
SN74AC14	Click here	Click here	Click here	Click here	Click here	

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-87624012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 87624012A SNJ54AC 14FK	Samples
5962-8762401CA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401CA SNJ54AC14J	Samples
5962-8762401DA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401DA SNJ54AC14W	Samples
5962-8762401VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401VC A SNV54AC14J	Samples
5962-8762401VDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401VD A SNV54AC14W	Samples
5962-8762402VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762402VC A SNV54AC14J	Samples
5962-8762402VDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762402VD A SNV54AC14W	Samples
SN74AC14DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC14	Samples
SN74AC14DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC14	Samples
SN74AC14N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74AC14N	Samples
SN74AC14NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC14	Samples
SN74AC14NSRG4	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC14	Samples
SN74AC14PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC14	Samples
SNJ54AC14FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 87624012A SNJ54AC 14FK	Samples

PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54AC14J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401CA SNJ54AC14J	Samples
SNJ54AC14W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8762401DA SNJ54AC14W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF SN54AC14, SN54AC14-SP, SN74AC14:

Catalog: SN74AC14, SN54AC14

Automotive: SN74AC14-Q1, SN74AC14-Q1

Military: SN54AC14

• Space : SN54AC14-SP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Military - QML certified for Military and Defense Applications

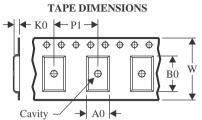
• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application



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TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AC14DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AC14NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AC14PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AC14DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AC14DR	SOIC	D	14	2500	333.2	345.9	28.6
SN74AC14DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AC14NSR	SO	NS	14	2000	356.0	356.0	35.0
SN74AC14PWR	TSSOP	PW	14	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-87624012A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-8762401DA	W	CFP	14	25	506.98	26.16	6220	NA
5962-8762401VDA	W	CFP	14	25	506.98	26.16	6220	NA
5962-8762402VDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74AC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AC14N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AC14FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AC14W	W	CFP	14	25	506.98	26.16	6220	NA

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



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